

# 74HC4017-Q100; 74HCT4017-Q100

Johnson decade counter with 10 decoded outputs

Rev. 2 — 1 July 2020

Product data sheet

## 1. General description

The 74HC4017-Q100; 74HCT4017-Q100 is a 5-stage Johnson decade counter with 10 decoded outputs (Q0 to Q9), an output from the most significant flip-flop ( $\overline{Q}5-9$ ), two clock inputs (CP0 and  $\overline{CP}1$ ) and an overriding asynchronous master reset input (MR). The counter is advanced by either a LOW-to-HIGH transition at CP0 while  $\overline{CP}1$  is LOW or a HIGH-to-LOW transition at  $\overline{CP}1$  while CP0 is HIGH. When cascading counters, the  $\overline{Q}5-9$  output, which is LOW while the counter is in states 5, 6, 7, 8 and 9, can be used to drive the CP0 input of the next counter. A HIGH on MR resets the counter to zero (Q0 =  $\overline{Q}5-9$  = HIGH; Q1 to Q9 = LOW) independent of the clock inputs (CP0 and  $\overline{CP}1$ ). Automatic code correction of the counter is provided by an internal circuit: following any illegal code the counter returns to a proper counting mode within 11 clock pulses. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- Input levels:
  - For 74HC4017-Q100: CMOS level
  - For 74HCT4017-Q100: TTL level
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

### 3. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74HC4017D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT4017D-Q100				
74HC4017PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HC4017BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1
74HCT4017BQ-Q100				

### 4. Functional diagram

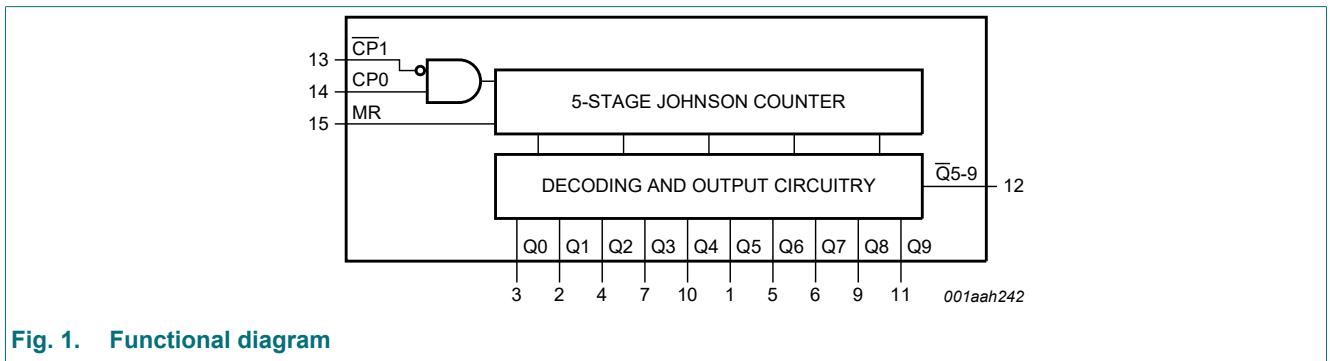


Fig. 1. Functional diagram

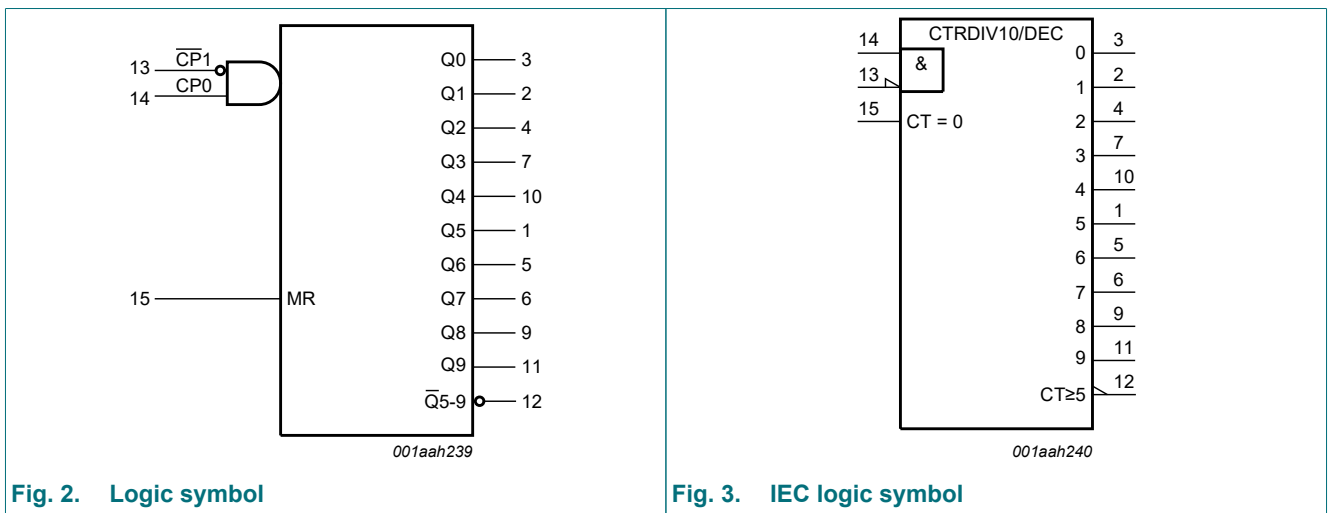


Fig. 2. Logic symbol

Fig. 3. IEC logic symbol

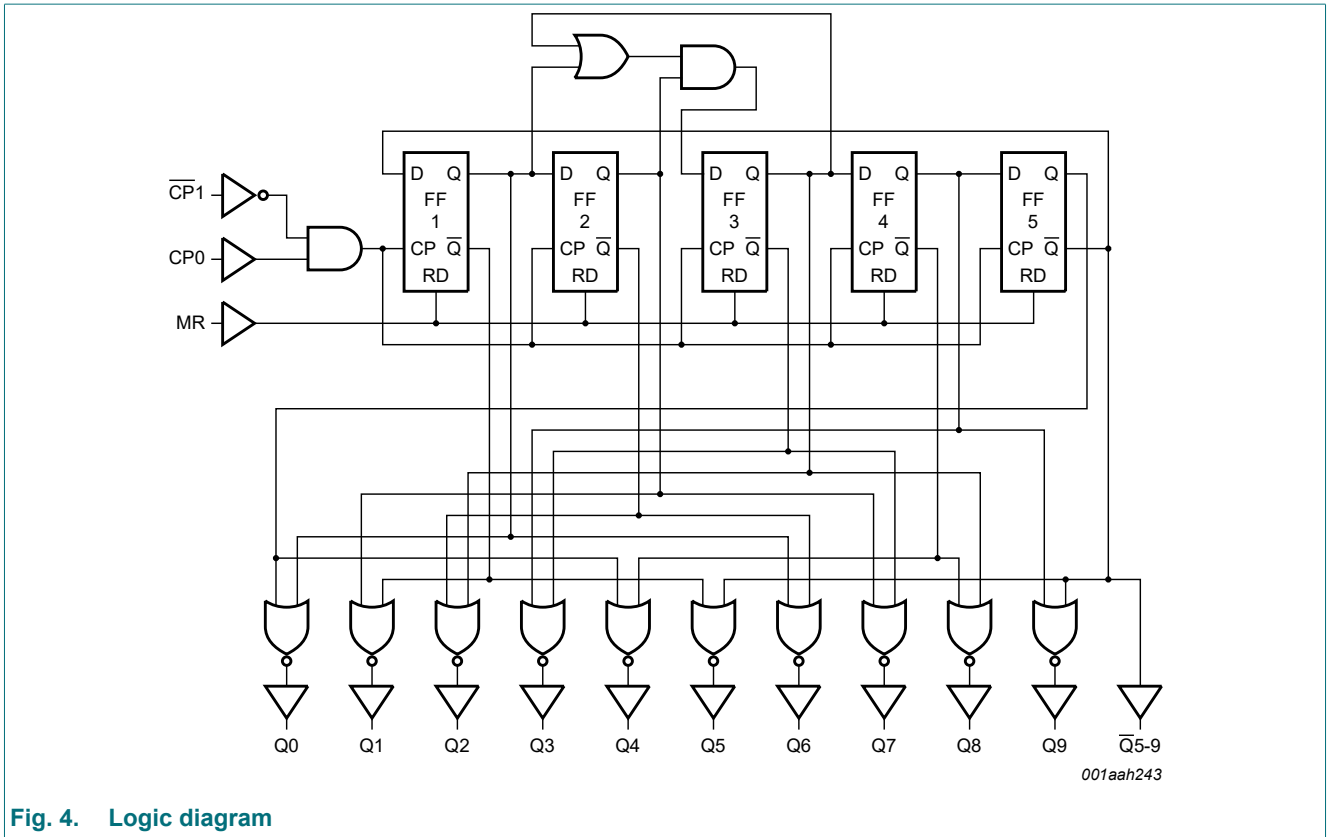


Fig. 4. Logic diagram

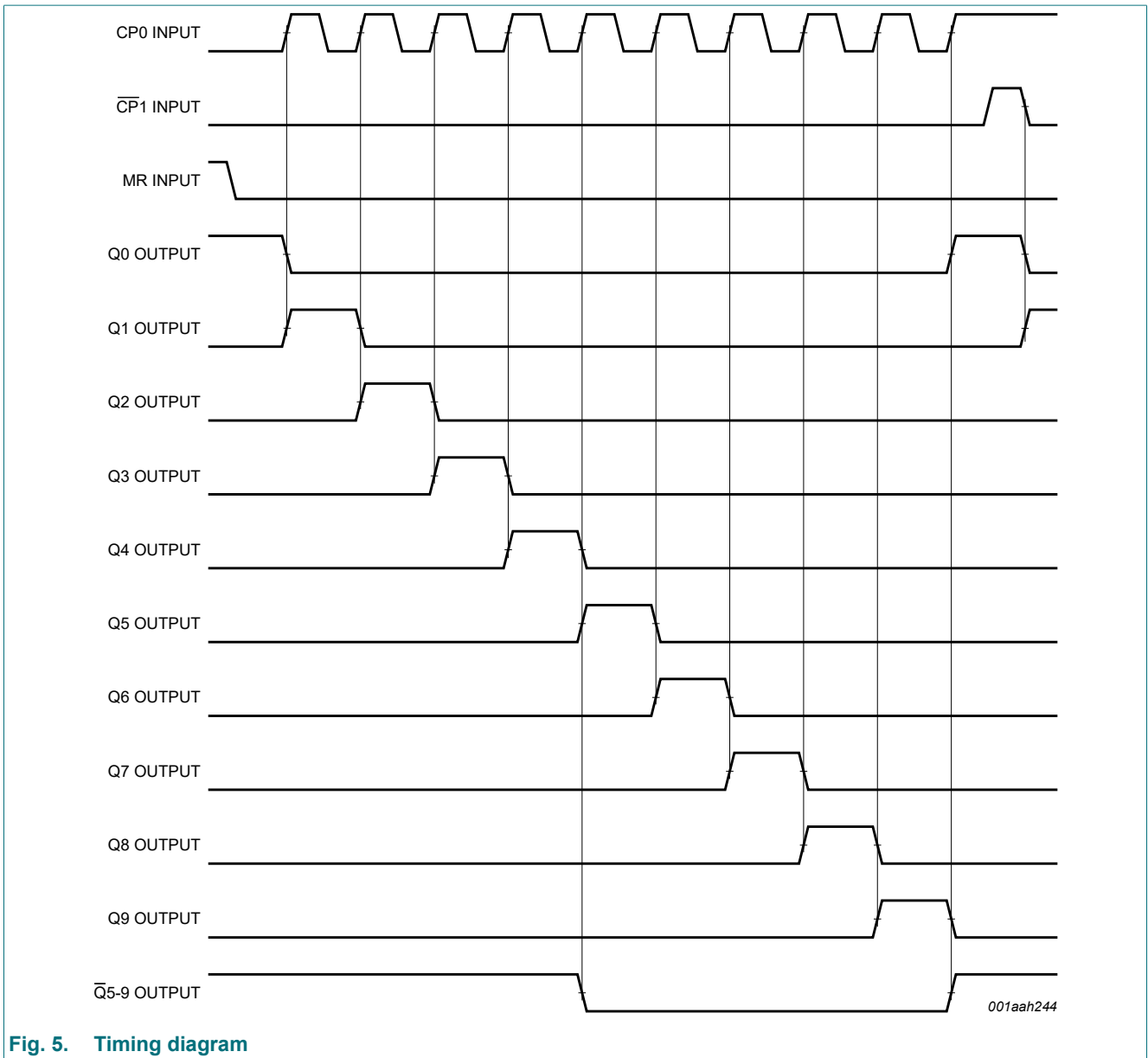
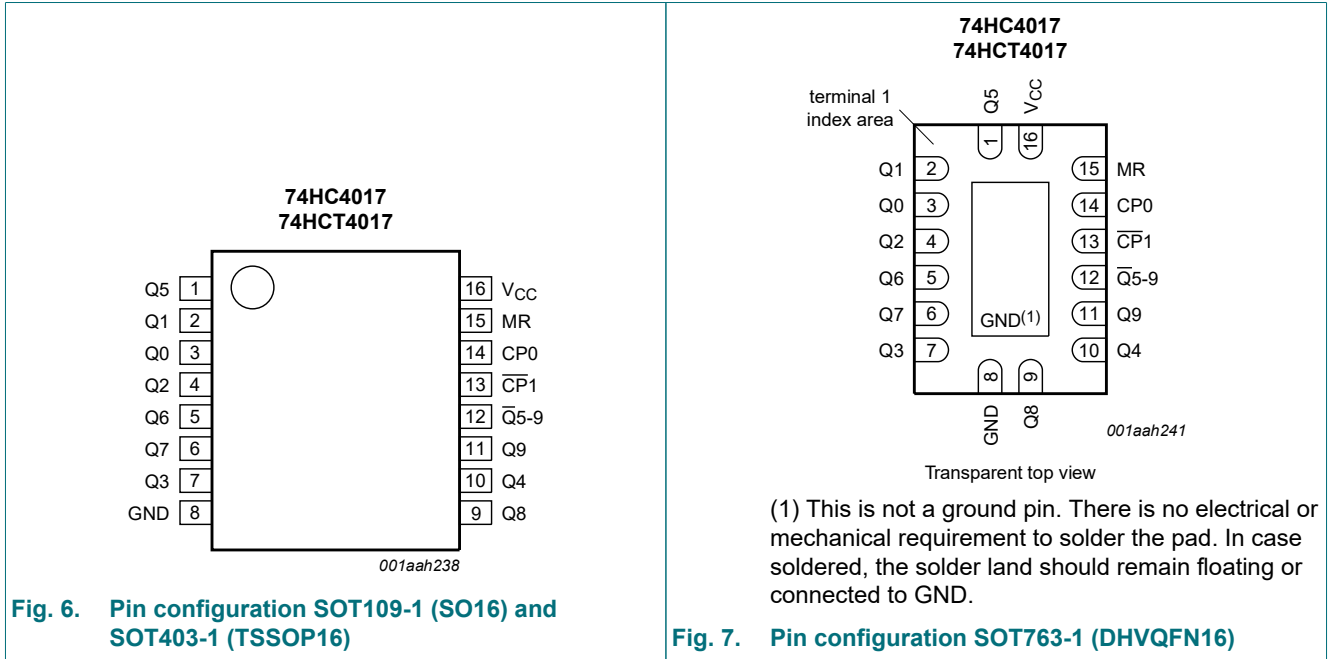


Fig. 5. Timing diagram

## 5. Pinning information

### 5.1. Pinning



### 5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7, Q8, Q9	3, 2, 4, 7, 10, 1, 5, 6, 9, 11	decoded output
GND	8	ground (0 V)
$\bar{Q}5-9$	12	carry output (active LOW)
$\bar{CP}1$	13	clock input (HIGH-to-LOW edge-triggered)
CP0	14	clock input (LOW-to-HIGH edge-triggered)
MR	15	master reset input (active HIGH)
V <sub>CC</sub>	16	supply voltage

## 6. Functional description

**Table 3. Function table**

H = HIGH voltage level; L = LOW voltage level; X = don't care; ↑ = LOW-to-HIGH transition; ↓ = HIGH-to-LOW transition;

MR	CP0	CP1	Operation
H	X	X	Q0 = Q5-9 = HIGH; Q1 to Q9 = LOW
L	H	↓	counter advances
L	↑	L	counter advances
L	L	X	no change
L	X	H	no change
L	H	↑	no change
L	↓	L	no change

## 7. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V [1]	-	±20	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V [1]	-	±20	mA
I <sub>O</sub>	output current	-0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C [2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C.  
 For SOT403-1 (TSSOP16) package: P<sub>tot</sub> derates linearly with 8.5 mW/K above 91 °C.  
 For SOT763-1 (DHVQFN16) package: P<sub>tot</sub> derates linearly with 11.2 mW/K above 106 °C.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	74HC4017-Q100			74HCT4017-Q100			Unit
			Min	Typ	Max	Min	Typ	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C

## 9. Static characteristics

**Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
<b>74HC4017-Q100</b>										
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V		
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V		
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	8.0	-	80	-	160	μA
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
<b>74HCT4017-Q100</b>										
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V								
		I <sub>O</sub> = -20 µA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V								
		I <sub>O</sub> = 20 µA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±0.1	-	±1.0	-	±1.0	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V; I <sub>O</sub> = 0 A	-	-	8.0	-	80	-	160	µA
ΔI <sub>CC</sub>	additional supply current	per input pin; V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A								
		CP0 input	-	25	90	-	113	-	123	µA
		$\overline{\text{CP}}1$ input	-	40	144	-	180	-	196	µA
		MR input	-	50	180	-	225	-	245	µA
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF



## 10. Dynamic characteristics

**Table 7. Dynamic characteristics**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ ; see [Fig. 11](#).

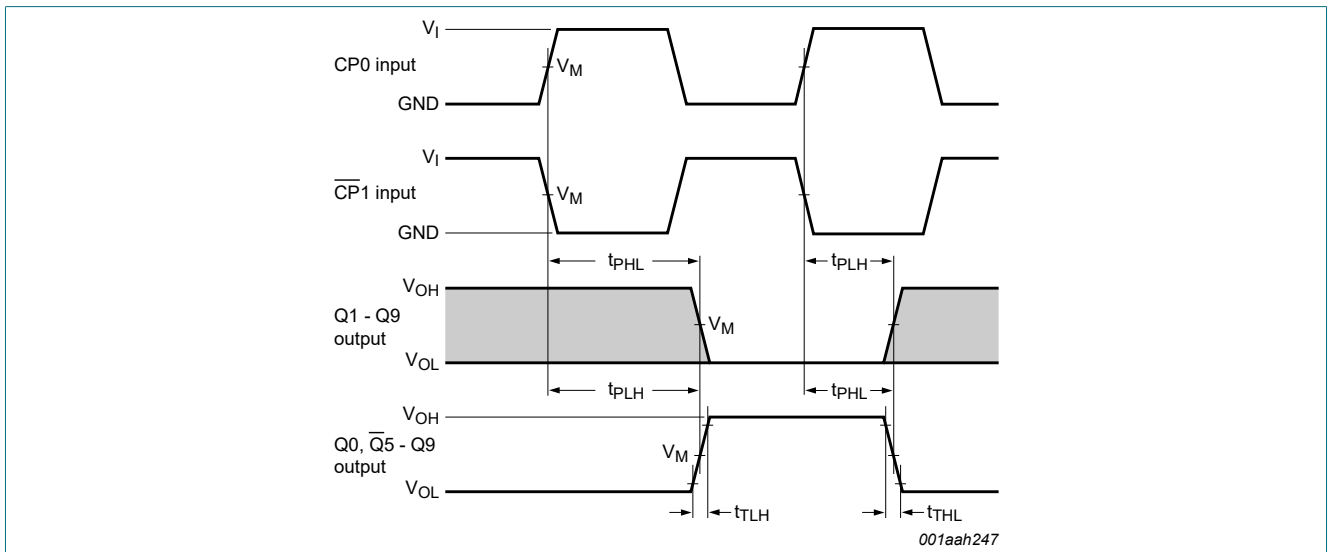
Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
<b>74HC4017-Q100</b>										
$t_{pd}$	propagation delay	CP0 to Qn; CP0 to $\overline{Q}5-9$ ; see <a href="#">Fig. 8</a> [1]								
		$V_{CC} = 2.0\text{ V}$	-	63	230	-	290	-	345	ns
		$V_{CC} = 4.5\text{ V}$	-	23	46	-	58	-	69	ns
		$V_{CC} = 5.0\text{ V}$ ; $C_L = 15\text{ pF}$	-	20	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	-	18	39	-	49	-	59	ns
		$\overline{CP}1$ to Qn; $\overline{CP}1$ to $\overline{Q}5-9$ ; see <a href="#">Fig. 8</a>								
		$V_{CC} = 2.0\text{ V}$	-	61	250	-	315	-	375	ns
		$V_{CC} = 4.5\text{ V}$	-	22	50	-	63	-	75	ns
		$V_{CC} = 5.0\text{ V}$ ; $C_L = 15\text{ pF}$	-	20	-	-	-	-	-	ns
$V_{CC} = 6.0\text{ V}$	-	18	43	-	54	-	64	ns		
$t_{PHL}$	HIGH to LOW propagation delay	MR to Qn; see <a href="#">Fig. 9</a>								
		$V_{CC} = 2.0\text{ V}$	-	52	230	-	290	-	345	ns
		$V_{CC} = 4.5\text{ V}$	-	19	46	-	58	-	69	ns
		$V_{CC} = 6.0\text{ V}$	-	15	39	-	49	-	59	ns
$t_{PLH}$	LOW to HIGH propagation delay	MR to $\overline{Q}5-9$ , Q0; see <a href="#">Fig. 9</a>								
		$V_{CC} = 2.0\text{ V}$	-	55	230	-	290	-	345	ns
		$V_{CC} = 4.5\text{ V}$	-	20	46	-	58	-	69	ns
		$V_{CC} = 6.0\text{ V}$	-	16	39	-	49	-	59	ns
$t_t$	transition time	see <a href="#">Fig. 8</a> [2]								
		$V_{CC} = 2.0\text{ V}$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5\text{ V}$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0\text{ V}$	-	6	13	-	16	-	19	ns
$t_w$	pulse width	CP0 and $\overline{CP}1$ (HIGH or LOW); see <a href="#">Fig. 9</a>								
		$V_{CC} = 2.0\text{ V}$	80	17	-	100	-	120	-	ns
		$V_{CC} = 4.5\text{ V}$	16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0\text{ V}$	14	5	-	17	-	20	-	ns
		MR (HIGH); see <a href="#">Fig. 9</a>								
		$V_{CC} = 2.0\text{ V}$	80	19	-	100	-	120	-	ns
		$V_{CC} = 4.5\text{ V}$	16	7	-	20	-	24	-	ns
		$V_{CC} = 6.0\text{ V}$	14	6	-	17	-	20	-	ns
$t_{su}$	set-up time	$\overline{CP}1$ to CP0; CP0 to $\overline{CP}1$ ; see <a href="#">Fig. 10</a>								
		$V_{CC} = 2.0\text{ V}$	50	-8	-	65	-	75	-	ns
		$V_{CC} = 4.5\text{ V}$	10	-3	-	13	-	15	-	ns
		$V_{CC} = 6.0\text{ V}$	9	-2	-	11	-	13	-	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ	Max	Min	Max	Min	Max		
t <sub>h</sub>	hold time	$\overline{CP1}$ to CP0; CP0 to $\overline{CP1}$ ; see <a href="#">Fig. 10</a>									
		V <sub>CC</sub> = 2.0 V	50	17	-	65	-	75	-	ns	
		V <sub>CC</sub> = 4.5 V	10	6	-	13	-	15	-	ns	
		V <sub>CC</sub> = 6.0 V	9	5	-	11	-	13	-	ns	
t <sub>rec</sub>	recovery time	MR to CP0 and MR to $\overline{CP1}$ ; see <a href="#">Fig. 9</a>									
		V <sub>CC</sub> = 2.0 V	5	-17	-	5	-	5	-	ns	
		V <sub>CC</sub> = 4.5 V	5	-6	-	5	-	5	-	ns	
		V <sub>CC</sub> = 6.0 V	5	-5	-	5	-	5	-	ns	
f <sub>max</sub>	maximum frequency	CP0 or $\overline{CP1}$ ; see <a href="#">Fig. 9</a>									
		V <sub>CC</sub> = 2.0 V	6.0	23	-	4.8	-	4.0	-	MHz	
		V <sub>CC</sub> = 4.5 V	30	70	-	24	-	20	-	MHz	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	77	-	-	-	-	-	MHz	
		V <sub>CC</sub> = 6.0 V	25	83	-	28	-	24	-	MHz	
C <sub>PD</sub>	power dissipation capacitance	V <sub>I</sub> = GND to V <sub>CC</sub> ; V <sub>CC</sub> = 5 V; [3] f <sub>i</sub> = 1 MHz	-	35	-	-	-	-	-	pF	
<b>74HCT4017-Q100</b>											
t <sub>pd</sub>	propagation delay	CP0 to Q <sub>n</sub> ; CP0 to $\overline{Q5-9}$ ; see <a href="#">Fig. 8</a> [1]									
		V <sub>CC</sub> = 4.5 V	-	25	46	-	58	-	69	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	21	-	-	-	-	-	ns	
		$\overline{CP1}$ to Q <sub>n</sub> ; $\overline{CP1}$ to $\overline{Q5-9}$ ; see <a href="#">Fig. 8</a>									
		V <sub>CC</sub> = 4.5 V	-	25	50	-	63	-	75	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	21	-	-	-	-	-	ns	
t <sub>PHL</sub>	HIGH to LOW propagation delay	MR to Q <sub>n</sub> ; see <a href="#">Fig. 9</a>									
		V <sub>CC</sub> = 4.5 V	-	22	46	-	58	-	69	ns	
t <sub>PLH</sub>	LOW to HIGH propagation delay	MR to $\overline{Q5-9}$ , Q0; see <a href="#">Fig. 9</a>									
		V <sub>CC</sub> = 4.5 V	-	20	46	-	58	-	69	ns	
t <sub>t</sub>	transition time	see <a href="#">Fig. 8</a> [2]									
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns	
t <sub>W</sub>	pulse width	CP0 and $\overline{CP1}$ (HIGH or LOW); see <a href="#">Fig. 9</a>									
		V <sub>CC</sub> = 4.5 V	16	7	-	20	-	24	-	ns	
		MR (HIGH); see <a href="#">Fig. 9</a>									
		V <sub>CC</sub> = 4.5 V	16	4	-	20	-	24	-	ns	
t <sub>su</sub>	set-up time	$\overline{CP1}$ to CP0; CP0 to $\overline{CP1}$ ; see <a href="#">Fig. 10</a>									
		V <sub>CC</sub> = 4.5 V	10	-3	-	13	-	15	-	ns	
t <sub>h</sub>	hold time	$\overline{CP1}$ to CP0; CP0 to $\overline{CP1}$ ; see <a href="#">Fig. 10</a>									
		V <sub>CC</sub> = 4.5 V	10	6	-	13	-	15	-	ns	

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t <sub>rec</sub>	recovery time	MR to CP0 and MR to $\overline{CP1}$ ; see Fig. 9								
		V <sub>CC</sub> = 4.5 V	5	-5	-	5	-	5	-	ns
f <sub>max</sub>	maximum frequency	CP0 or $\overline{CP1}$ ; see Fig. 9								
		V <sub>CC</sub> = 4.5 V	30	61	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	67	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	V <sub>I</sub> = GND to V <sub>CC</sub> - 1.5 V; V <sub>CC</sub> = 5 V; f <sub>i</sub> = 1 MHz [3]	-	36	-	-	-	-	-	pF

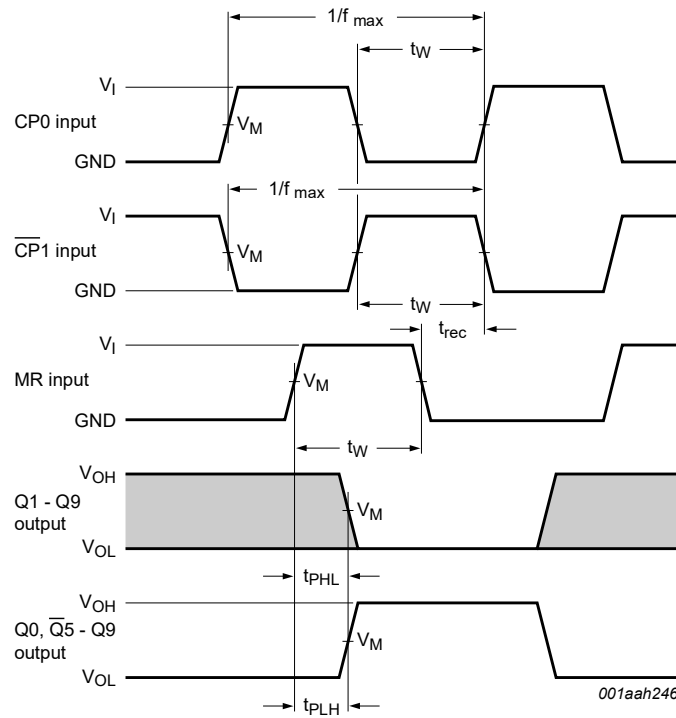
- [1] t<sub>pd</sub> is the same as t<sub>PHL</sub> and t<sub>PLH</sub>.
- [2] t<sub>i</sub> is the same as t<sub>THL</sub> and t<sub>TLH</sub>.
- [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW):  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = output load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### 10.1. Waveforms and test circuit



Measurement points are given in Table 8.  
 V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.  
 Conditions: CP1 = LOW while CP0 is triggered on a LOW-to-HIGH transition and CP0 = HIGH, while  $\overline{CP1}$  is triggered on a HIGH-to-LOW transition.

**Fig. 8. Waveforms showing the propagation delays for CP0,  $\overline{CP1}$  to Qn,  $\overline{Q5-9}$  outputs and the output transition times**



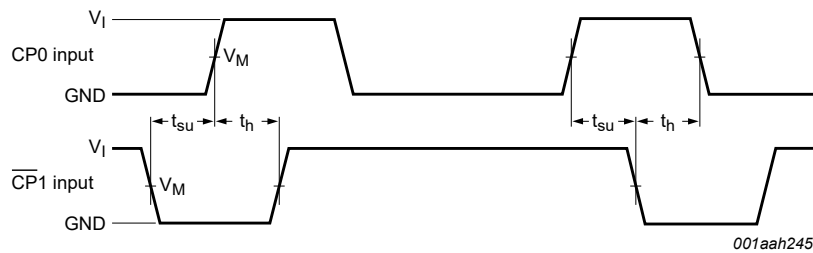
Measurement points are given in [Table 8](#).

$V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig. 9.** Waveforms showing the minimum pulse width for CP0, CP1 and MR input; the maximum frequency for CP0 and CP1 input; the recovery time for MR and the MR input to Qn and Q5-9 output propagation delays

**Table 8. Measurement points**

Type	Input	Output
	$V_M$	$V_M$
74HC4017-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74HCT4017-Q100	1.3 V	1.3 V



Measurement points are given in [Table 8](#).

$V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig. 10.** Waveforms showing the set-up and hold times for CP0 to CP1 and CP1 to CP0

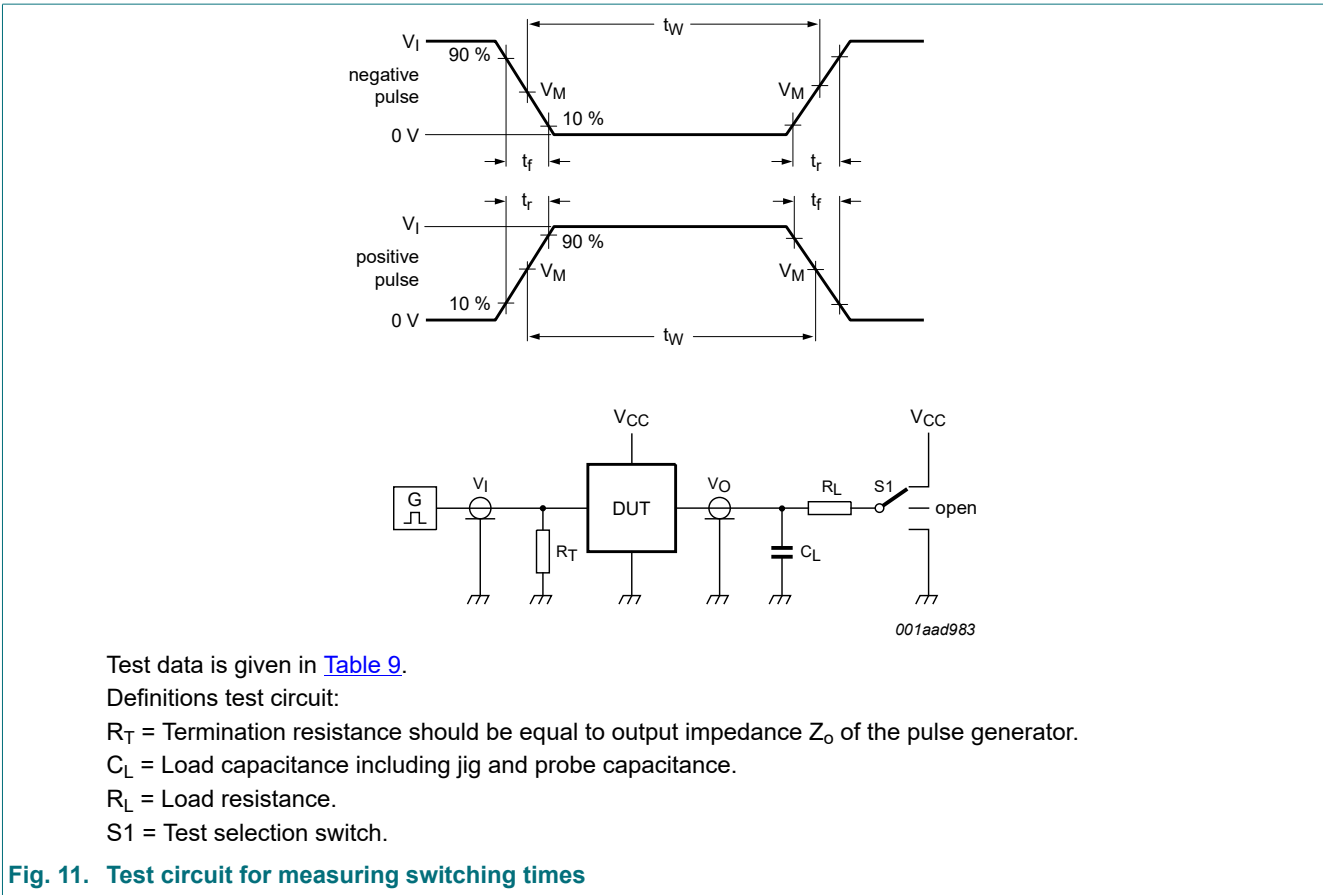


Fig. 11. Test circuit for measuring switching times

Table 9. Test data

Type	Input		Load		S1 position		
	$V_I$	$t_r, t_f$	$C_L$	$R_L$	$t_{PHL}, t_{PLH}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$
74HC4017-Q100	$V_{CC}$	6 ns	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$
74HCT4017-Q100	3 V	6 ns	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$

## 11. Application information

Some examples of applications for the 74HC4017-Q100; 74HCT4017-Q100 are:

- Decade counter with decimal decoding
- 1 out of n decoding counter (when cascaded)
- Sequential controller
- Timer

Fig. 12 shows a technique for extending the number of decoded output states for the 74HC4017-Q100; 74HCT4017-Q100. Decoded outputs are sequential within each stage and from stage to stage, with no dead time (except propagation delay).

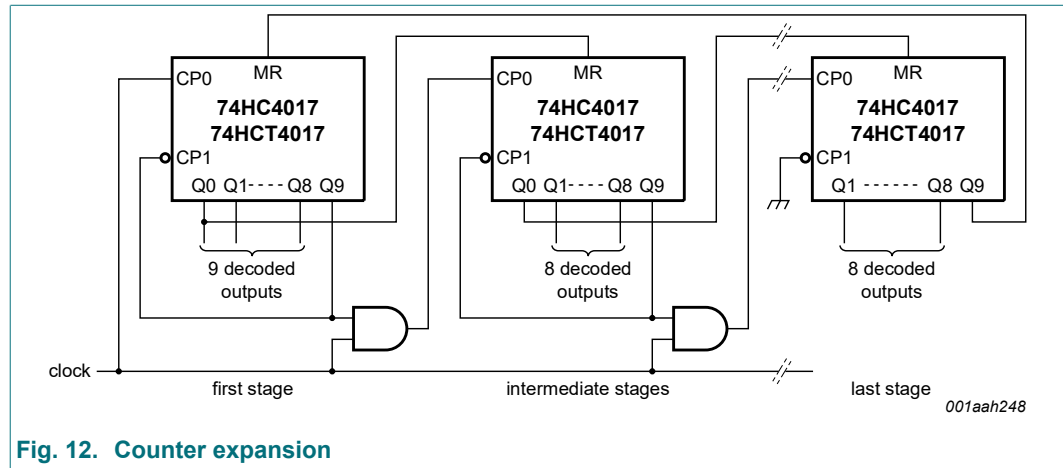


Fig. 12. Counter expansion

**Remark:** It is essential not to enable the counter on  $\overline{CP1}$  when  $CP0$  is HIGH, or on  $CP0$  when  $\overline{CP1}$  is LOW, as this would cause an extra count.

Fig. 13 shows an example of a divide-by 2 through divide-by 10 circuit using one 74HC4017-Q100; 74HCT4017-Q100. Since the 74HC4017-Q100; 74HCT4017-Q100 has an asynchronous reset, the output pulse widths are narrow (minimum expected pulse width is 6 ns). The output pulse widths can be enlarged by inserting an RC network at the MR input.

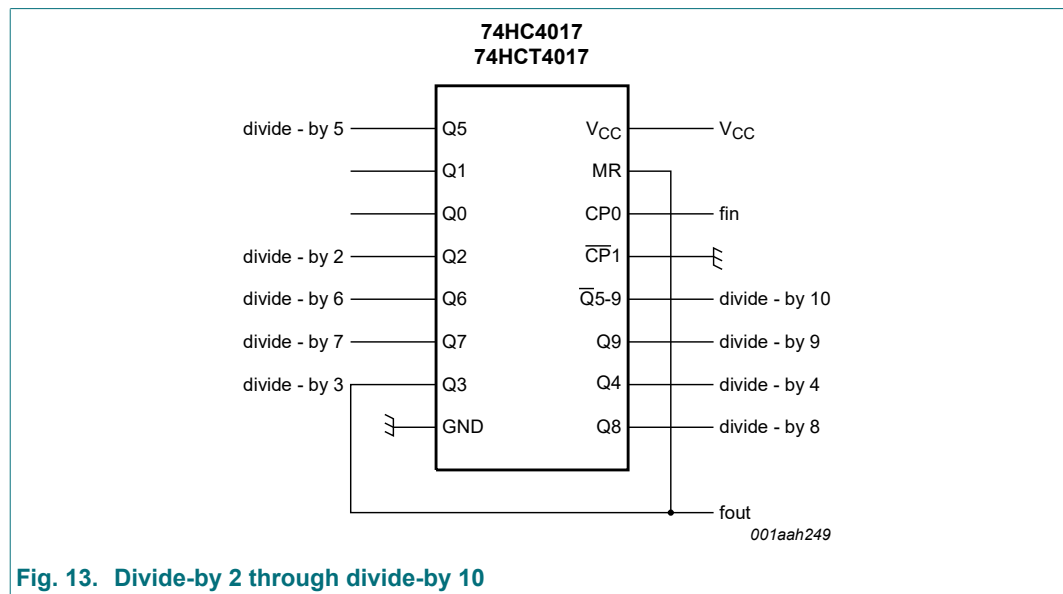


Fig. 13. Divide-by 2 through divide-by 10

## 12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Fig. 14. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Fig. 15. Package outline SOT403-1 (TSSOP16)



DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm

SOT763-1



Fig. 16. Package outline SOT763-1 (DHVQFN16)

## 13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

## 14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4017_Q100 v.2	20200701	Product data sheet	-	74HC_HCT4017_Q100 v.1
Modifications:	<ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><a href="#">Section 1</a> and <a href="#">Section 2</a> updated.</li> <li><a href="#">Table 4</a>: Derating values for <math>P_{tot}</math> total power dissipation have been updated.</li> </ul>			
74HC_HCT4017_Q100 v.1	20140324	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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## Contents

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<b>1. General description</b> .....	<b>1</b>
<b>2. Features and benefits</b> .....	<b>1</b>
<b>3. Ordering information</b> .....	<b>2</b>
<b>4. Functional diagram</b> .....	<b>2</b>
<b>5. Pinning information</b> .....	<b>5</b>
5.1. Pinning.....	5
5.2. Pin description.....	5
<b>6. Functional description</b> .....	<b>6</b>
<b>7. Limiting values</b> .....	<b>6</b>
<b>8. Recommended operating conditions</b> .....	<b>6</b>
<b>9. Static characteristics</b> .....	<b>7</b>
<b>10. Dynamic characteristics</b> .....	<b>9</b>
10.1. Waveforms and test circuit.....	11
<b>11. Application information</b> .....	<b>14</b>
<b>12. Package outline</b> .....	<b>15</b>
<b>13. Abbreviations</b> .....	<b>18</b>
<b>14. Revision history</b> .....	<b>18</b>
<b>15. Legal information</b> .....	<b>19</b>

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